

M•C

Micro Commercial Corp.
21201 Itasca St.
Chatsworth, CA 91311
Phone: (818) 701-4933
Fax: (818) 701-4939

Features

- Low Current Leakage
- Compression Bond Construction
- Low Cost

Maximum Ratings

- Operating Temperature: -65°C to +175°C
- Storage Temperature: -65°C to +175°C
- Maximum Thermal Resistance: 35°C/W Junction To Ambient

Electrical Characteristics @ 25°C Unless Otherwise Specified

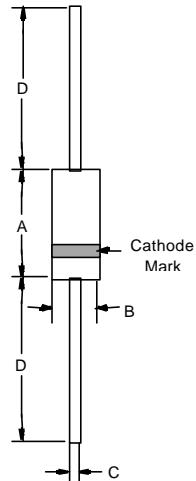
Reverse Voltage	V_R	75V	
Peak Reverse Voltage	V_{RM}	100V	
Average Rectified Current	I_O	150mA	Resistive Load $f > 50\text{Hz}$
Power Dissipation	P_{TOT}	500mW	
Junction Temperature	T_J	200°C	
Peak Forward Surge Current	I_{FSM}	500mA	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1.0V	$I_{FM} = 10\text{mA};$ $T_J = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	25nA 50 μA	$V_R=20\text{Volts}$ $T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$
Typical Junction Capacitance	C_J	4pF	Measured at 1.0MHz, $V_R=4.0\text{V}$
Reverse Recovery Time	T_{rr}	4nS	$I_F=10\text{mA}$ $V_R = 6\text{V}$ $R_L=100\Omega$

*Pulse test: Pulse width 300 μsec , Duty cycle 2%

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**500mW 100 Volt
Silicon Epitaxial Diode**

DO-35

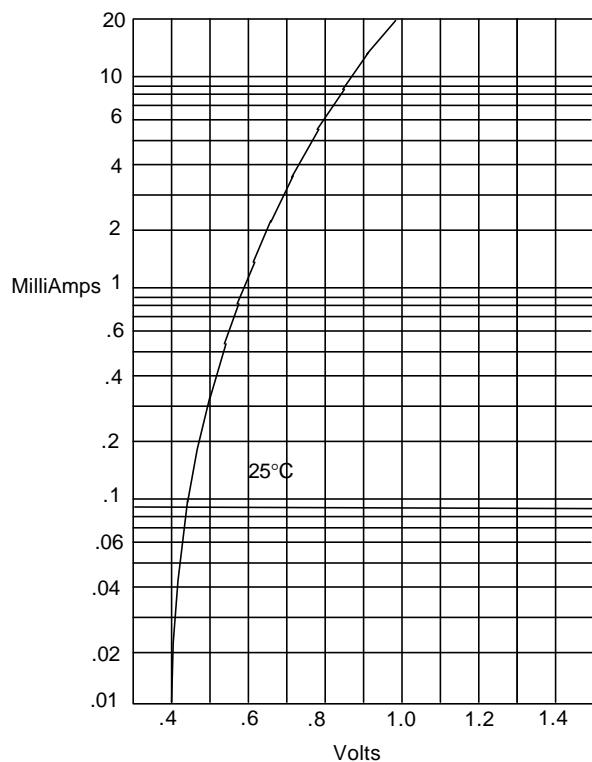


DIM	DIMENSIONS				
	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	--	.166	--	4.2	
B	--	.079	--	2.00	
C	--	.020	--	.52	
D	1.000	--	25.40	--	

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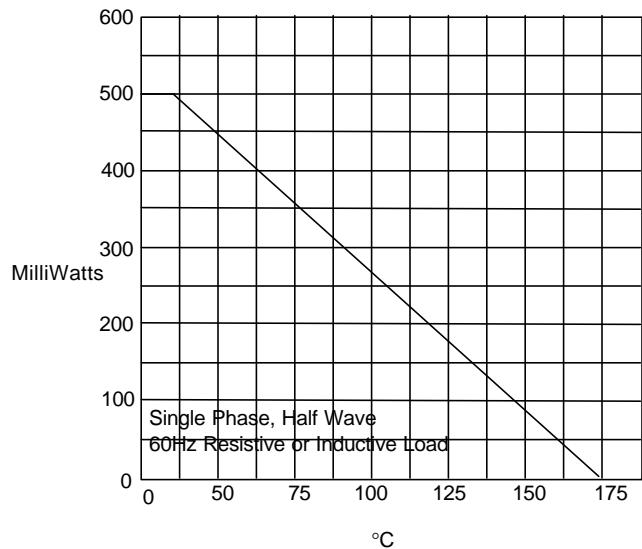
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Figure 1
Typical Forward Characteristics



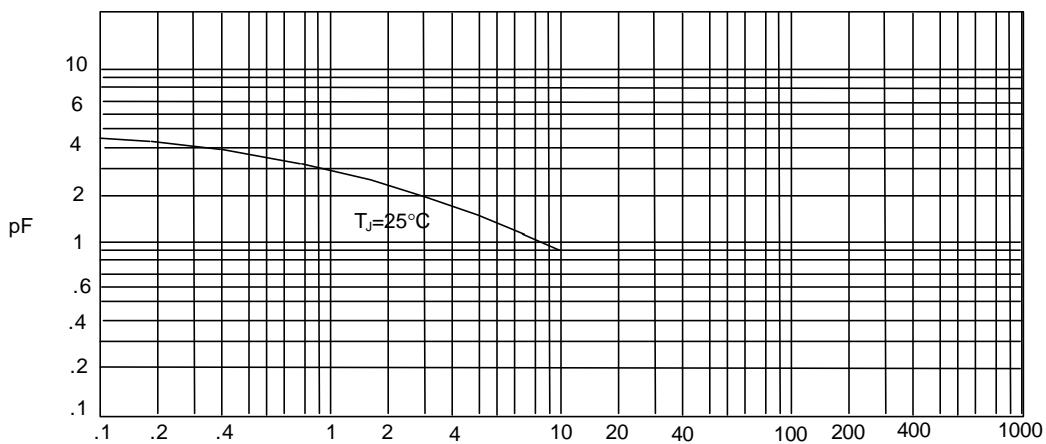
Instantaneous Forward Current - Amperes versus
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



Admissible Power Dissipation - MilliWatts versus
Ambient Temperature - °C

Figure 3
Junction Capacitance

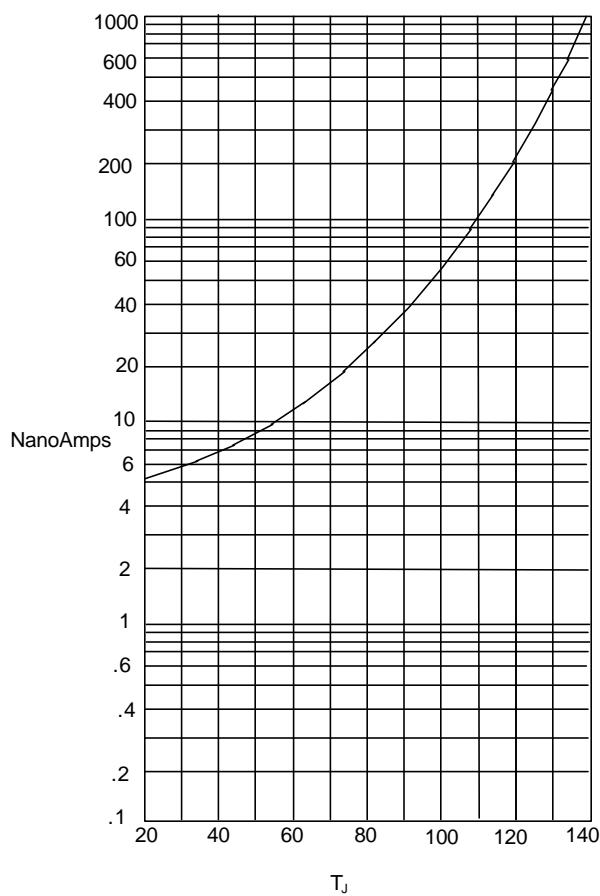


Junction Capacitance - pF versus
Reverse Voltage - Volts

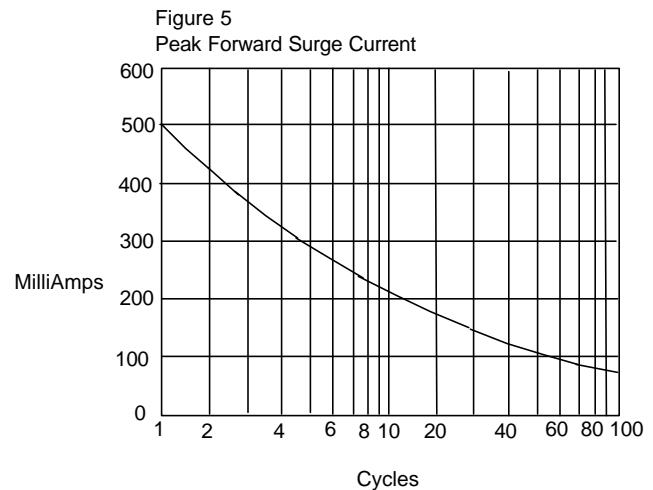
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Figure 4
Typical Reverse Characteristics



Instantaneous Reverse Leakage Current - NanoAmperes versus
Junction Temperature - °C



Peak Forward Surge Current - Amperes versus
Number Of Cycles At 60Hz - Cycles

$T_A=25^\circ\text{C}$

$T_A=100^\circ\text{C}$